

3.3V CMOS 1-BIT TO 2-BIT ADDRESS DRIVER WITH 3-STATE OUTPUTS AND BUS-HOLD

IDT74ALVCHS162830

FEATURES:

- 0.5 MICRON CMOS Technology
- Typical tsk(o) (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- Vcc = 3.3V ± 0.3V, Normal Range
- Vcc = 2.7V to 3.6V, Extended Range
- $Vcc = 2.5V \pm 0.2V$
- CMOS power levels (0.4 w typ. static)
- · Rail-to-Rail output swing for increased noise margin
- Available in TVSOP package

DRIVE FEATURES:

- · Balanced Output Drivers: ±12mA
- · Low switching noise

APPLICATIONS:

- SDRAM Modules
- · PC Motherboards
- Workstations

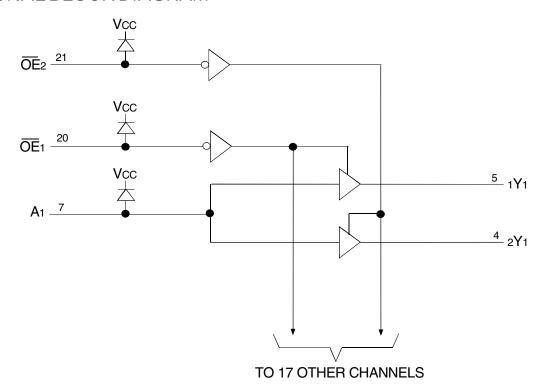
DESCRIPTION:

This 1-bit to 2-bit address driver is built using advanced dual metal CMOS technology. Diodes to Vcc have been added on the inputs to clamp overshoot.

The ALVCHS162830 has series resistors in the device output structure which will significantly reduce line noise when used with light loads. This driver has been designed to drive ± 12 mA at the designated threshold levels.

The ALVCHS162830 has "bus-hold" which retains the inputs' last state whenever the input bus goes to a high impedance. This prevents floating inputs and eliminates the need for pull-up/down resistors.

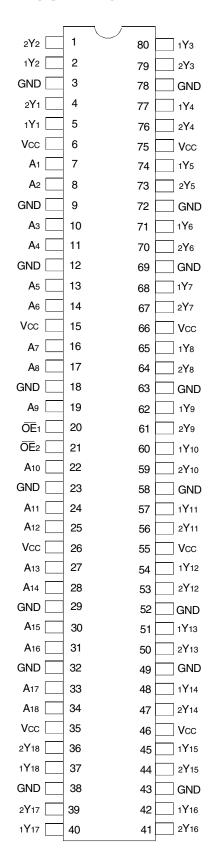
FUNCTIONAL BLOCK DIAGRAM



INDUSTRIAL TEMPERATURE RANGE

OCTOBER 1999

PIN CONFIGURATION



TVSOP TOP VIEW

ABSOLUTE MAXIMUM RATINGS(1)

Symbol	Description	Max	Unit
VTERM ⁽²⁾	Terminal Voltage with Respect to GND	-0.5 to +4.6	V
VTERM ⁽³⁾	Terminal Voltage with Respect to GND	-0.5 to Vcc+0.5	V
Tstg	Storage Temperature	-65 to +150	°C
Іоит	DC Output Current	-50 to +50	mA
lıĸ	Continuous Clamp Current, VI < 0 or VI > VCC	±50	mA
Іок	Continuous Clamp Current, Vo < 0	-50	mA
lcc Iss	Continuous Current through each Vcc or GND	±100	mA

NOTES:

- 1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- 2. Vcc terminals.
- 3. All terminals except Vcc.

CAPACITANCE (TA = +25°C, F = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Тур.	Max.	Unit
CIN	Input Capacitance	VIN = 0V	5	7	pF
Соит	Output Capacitance	Vout = 0V	7	9	pF
Соит	I/O Port Capacitance	VIN = 0V	7	9	pF

NOTE:

1. As applicable to the device type.

PIN DESCRIPTION

Pin Names	Description		
ŌĒx	3-State Output Enable Inputs (Active LOW)		
Ах	Data Inputs ⁽¹⁾		
хҮх	3-State Outputs		

NOTE:

1. These pins have "Bus-Hold". All other pins are standard inputs, outputs, or I/Os.

FUNCTION TABLE(1)

	Inputs		Out	outs
OE1	OE ₂	Ах	1YX	2 Y X
L	Н	Н	Н	Z
L	Н	L	L	Z
Н	L	Н	Z	Н
Н	L	L	Z	L
L	L	Н	Н	Н
L	L	L	Ĺ	L
Н	Н	Χ	Z	Z

NOTE:

- 1. H = HIGH Voltage Level
 - L = LOW Voltage Level
- X = Don't Care
- Z = High Impedance

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: $TA = -40^{\circ}C$ to $+85^{\circ}C$

Symbol	Parameter	Test Con	ditions	Min.	Typ. ⁽¹⁾	Max.	Unit
VIH	Input HIGH Voltage Level	Vcc = 2.3V to 2.7V		1.7	_	_	V
		Vcc = 2.7V to 3.6V		2	_	_	
VIL	Input LOW Voltage Level	Vcc = 2.3V to 2.7V		_	_	0.7	V
		Vcc = 2.7V to 3.6V		_	_	0.8	
Іін	Input HIGH Current	Vcc = 3.6V	VI = VCC	_	_	±5	μA
liL	Input LOW Current	Vcc = 3.6V	VI = GND	_	_	±5	μA
Іоzн	High Impedance Output Current	Vcc = 3.6V	Vo = Vcc	_	_	±10	μA
lozl	(3-State Output pins)		Vo = GND	_	_	±10	
Vik	Clamp Diode Voltage	VCC = 2.3V, IIN = -18mA		_	-0.7	-1.2	V
Vн	Input Hysteresis	Vcc = 3.3V		_	100	_	mV
ICCL ICCH ICCZ	Quiescent Power Supply Current	Vcc = 3.6V Vin = GND or Vcc		_	0.1	40	μА
∆lcc	Quiescent Power Supply Current Variation	One input at Vcc - 0.6V, other in	puts at Vcc or GND	_	_	750	μА

NOTE:

BUS-HOLD CHARACTERISTICS

Symbol	Parameter ⁽¹⁾	Test Conditions		Min.	Typ. ⁽²⁾	Max.	Unit
Івнн	Bus-Hold Input Sustain Current	Vcc = 3V	VI = 2V	- 75	_	_	μA
IBHL			VI = 0.8V	75		1	
Івнн	Bus-Hold Input Sustain Current	Vcc = 2.3V	Vı = 1.7V	- 45			μA
IBHL			VI = 0.7V	45	_	-	
Івнно	Bus-Hold Input Overdrive Current	Vcc = 3.6V	VI = 0 to 3.6V	_	_	±500	μA
Івньо							

NOTES:

- 1. Pins with Bus-Hold are identified in the pin description.
- 2. Typical values are at Vcc = 3.3V, +25°C ambient.

^{1.} Typical values are at Vcc = 3.3V, +25°C ambient.

OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	Test Con	nditions ⁽¹⁾	Min.	Max.	Unit
Vон	Output HIGH Voltage	Vcc = 2.3V to 3.6V	IOH = - 0.1mA	Vcc-0.2	_	V
		Vcc = 2.3V	IOH = -4mA	1.9	_	
			IOH = -6mA	1.7	_	
		Vcc = 2.7V	IOH = -4mA	2.2	_	
			IOH = -8mA	2	_	
		Vcc = 3V	IOH = -6mA	2.4	_	
			IOH = - 12mA	2	_	
Vol	Output LOW Voltage	Vcc = 2.3V to 3.6V	IoL = 0.1mA	_	0.2	V
		Vcc = 2.3V	IoL = 4mA	_	0.4	
			IoL = 6mA	_	0.55	
		Vcc = 2.7V	IoL = 4mA	_	0.4	
			IoL = 8mA	_	0.6	
		Vcc = 3V	IOL = 6mA	_	0.55	
			IOL = 12mA	_	0.8	

NOTE:

OPERATING CHARACTERISTICS, TA = 25°C

			Vcc = 2.5V ± 0.2V	$Vcc = 3.3V \pm 0.3V$	
Symbol	Parameter	Test Conditions	Typical	Typical	Unit
CPD	Power Dissipation Capacitance per Driver Outputs enabled	CL = 0pF, f = 10Mhz	49	53	pF
CPD	Power Dissipation Capacitance per Driver Outputs disabled		6	7.5	

SWITCHING CHARACTERISTICS(1)

		Vcc = 2.	5V ± 0.2V	Vcc =	= 2.7V	Vcc = 3.3	3V ± 0.3V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Unit
tplh	Propagation Delay	1.2	3.8	_	4	1.7	3.5	ns
tPHL	Ax to xYx							
tpzh	Output Enable Time	1	5.7	_	5.7	1	4.8	ns
tpzl	OEx to xYx							
tphz	Output Disable Time	1	4.9	_	5.4	1.7	5.2	ns
tPLZ	OEx to xYx							
tsk(o)	Output Skew ⁽²⁾	_	_	_	_	_	500	ps

NOTES:

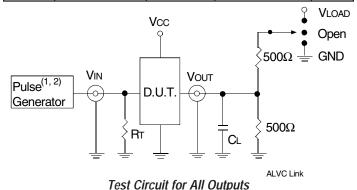
- 1. See TEST CIRCUITS AND WAVEFORMS. $TA = -40^{\circ}C$ to $+85^{\circ}C$.
- 2 Skew between any two outputs of the same package and switching in the same direction.

^{1.} VIH and VIL must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate Vcc range. TA = - 40°C to + 85°C.

TEST CIRCUITS AND WAVEFORMS

TEST CONDITIONS

Symbol	$Vcc^{(1)} = 3.3V \pm 0.3V$	Vcc ⁽¹⁾ = 2.7V	Vcc ⁽²⁾ = 2.5V±0.2V	Unit
VLOAD	6	6	2 x Vcc	V
VIH	2.7	2.7	Vcc	V
VT	1.5	1.5	Vcc / 2	V
VLZ	300	300	150	mV
VHZ	300	300	150	mV
CL	50	50	30	pF



DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.

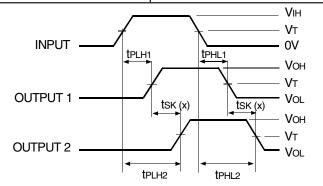
RT = Termination resistance: should be equal to ZouT of the Pulse Generator.

NOTES:

- 1. Pulse Generator for All Pulses: Rate \leq 1.0MHz; tr \leq 2.5ns; tr \leq 2.5ns.
- 2. Pulse Generator for All Pulses: Rate \leq 1.0MHz; tF \leq 2ns; tR \leq 2ns.

SWITCH POSITION

Test	Switch
Open Drain Disable Low Enable Low	VLOAD
Disable High Enable High	GND
All Other Tests	Open

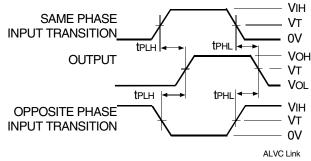


tsk(x) = |tPLH2 - tPLH1| or |tPHL2 - tPHL1|ALVC Link

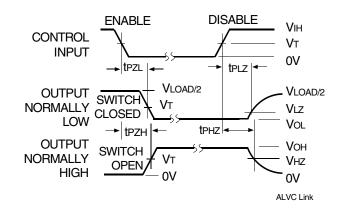
Output Skew - tsk(x)

NOTES:

- 1. For tsk(o) OUTPUT1 and OUTPUT2 are any two outputs.
- 2. For tsk(b) OUTPUT1 and OUTPUT2 are in the same bank.



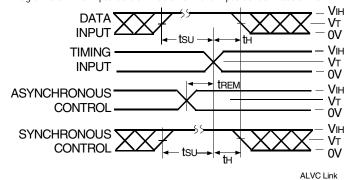
Propagation Delay



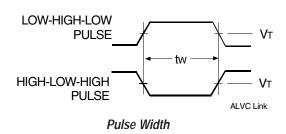
Enable and Disable Times

NOTE:

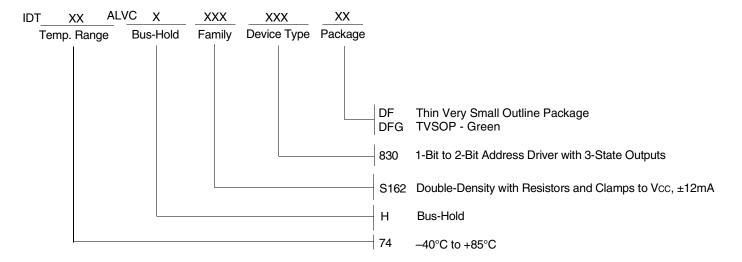
1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.



Set-up, Hold, and Release Times



ORDERING INFORMATION



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